

FMG2G200US60

Molding Type Module

General Description

Fairchild IGBT Power Module provides low conduction and switching losses as well as short circuit ruggedness. It's designed for the applications such as motor control, uninterrupt power supplies (UPS) and general inverters where short-circuit ruggedness is required.

Features

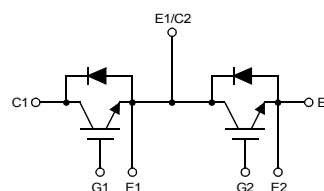
- Short Circuit Rated Time; 10us @ $T_C = 100^\circ\text{C}$, $V_{GE} = 15\text{V}$
- High Speed Switching
- Low Saturation Voltage : $V_{CE(sat)} = 2.1\text{V}$ @ $I_C = 200\text{A}$
- High Input Impedance
- Fast & Soft Anti-Parallel FWD
- UL Certified No.E209204

Application

- AC & DC Motor Controls
- General Purpose Inverters
- Robotics
- Servo Controls
- UPS



Package Code : 7PM-HA



Internal Circuit Diagram

Absolute Maximum Ratings

$T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Description	FMG2G200US60	Units
V_{CES}	Collector-Emitter Voltage	600	V
V_{GES}	Gate-Emitter Voltage	± 20	V
I_C	Collector Current @ $T_C = 80^\circ\text{C}$	200	A
$I_{CM(1)}$	Pulsed Collector Current	400	A
I_F	Diode Continuous Forward Current @ $T_C = 80^\circ\text{C}$	200	A
I_{FM}	Diode Maximum Forward Current	400	A
P_D	Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$	695	W
T_{SC}	Short Circuit Withstand Time @ $T_C = 100^\circ\text{C}$	10	us
T_J	Operating Junction Temperature	-40 to +150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-40 to +125	$^\circ\text{C}$
V_{ISO}	Isolation Voltage @ AC 1minute	2500	V
Mounting Torque	Power Terminal Screw : M5	4.0	N.m
	Mounting Screw : M6	4.0	N.m

Notes :

(1) Repetitive rating : Pulse width limited by max. junction temperature

Electrical Characteristics of IGBT $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
Off Characteristics						
BV_{CES}	Collector-Emitter Breakdown Voltage	$V_{GE} = 0V, I_C = 250\mu A$	600	--	--	V
$\Delta BV_{CES} / \Delta T_J$	Temperature Coeff. of Breakdown Voltage	$V_{GE} = 0V, I_C = 1mA$	--	0.6	--	$V/^\circ C$
I_{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$	--	--	250	μA
I_{GES}	Gate - Emitter Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$	--	--	± 100	nA

On Characteristics

$V_{GE(th)}$	Gate - Emitter Threshold Voltage	$I_C = 200mA, V_{CE} = V_{GE}$	5.0	6.5	8.5	V
$V_{CE(sat)}$	Collector to Emitter Saturation Voltage	$I_C = 200A, V_{GE} = 15V$	--	2.1	2.7	V

Switching Characteristics

$t_{d(on)}$	Turn-On Delay Time	$V_{CC} = 300V, I_C = 200A,$ $R_G = 2\Omega, V_{GE} = 15V,$ Inductive Load, $T_C = 25^\circ C$	--	80	--	ns
t_r	Rise Time		--	120	--	ns
$t_{d(off)}$	Turn-Off Delay Time		--	130	--	ns
t_f	Fall Time		--	130	250	ns
E_{on}	Turn-On Switching Loss		--	2.7	--	mJ
E_{off}	Turn-Off Switching Loss	$V_{CC} = 300V, I_C = 200A,$ $R_G = 2\Omega, V_{GE} = 15V,$ Inductive Load, $T_C = 125^\circ C$	--	6.0	--	mJ
$t_{d(on)}$	Turn-On Delay Time		--	200	--	ns
t_r	Rise Time		--	130	--	ns
$t_{d(off)}$	Turn-Off Delay Time		--	170	--	ns
t_f	Fall Time		--	240	--	ns
E_{on}	Turn-On Switching Loss		--	4.4	--	mJ
E_{off}	Turn-Off Switching Loss		--	10.5	--	mJ
T_{sc}	Short Circuit Withstand Time	$V_{CC} = 300V, V_{GE} = 15V$ @ $T_C = 100^\circ C$	10	--	--	us
Q_g	Total Gate Charge	$V_{CE} = 300V, I_C = 200A,$ $V_{GE} = 15V$	--	625	--	nC
Q_{ge}	Gate-Emitter Charge		--	150	--	nC
Q_{gc}	Gate-Collector Charge		--	215	--	nC

Electrical Characteristics of DIODE $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Units
V _{FM}	Diode Forward Voltage	I _F = 200A	T _C = 25°C	--	1.9	2.8	V
			T _C = 100°C	--	1.8	--	
t _{rr}	Diode Reverse Recovery Time	I _F = 200A di / dt = 400 A/us	T _C = 25°C	--	90	130	ns
			T _C = 100°C	--	130	--	
I _{rr}	Diode Peak Reverse Recovery Current		T _C = 25°C	--	19	25	A
			T _C = 100°C	--	25	--	
Q _{rr}	Diode Reverse Recovery Charge		T _C = 25°C	--	855	1600	nC
			T _C = 100°C	--	1625	--	

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Units
$R_{\theta JC}$	Junction-to-Case (IGBT Part, per 1/2 Module)	--	0.18	$^\circ C/W$
$R_{\theta JC}$	Junction-to-Case (DIODE Part, per 1/2 Module)	--	0.37	$^\circ C/W$
$R_{\theta JC}$	Case-to-Sink (Conductive grease applied)	0.04	--	$^\circ C/W$
Weight	Weight of Module	240	--	g

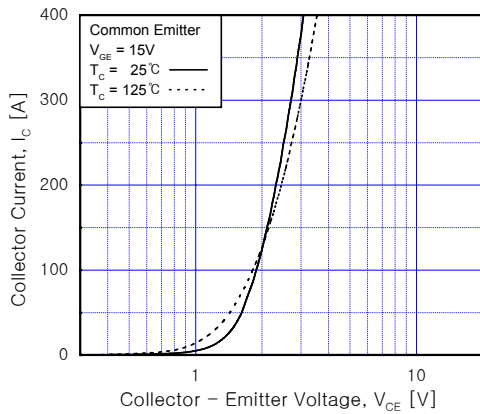


Fig 1. Typical Output Characteristics

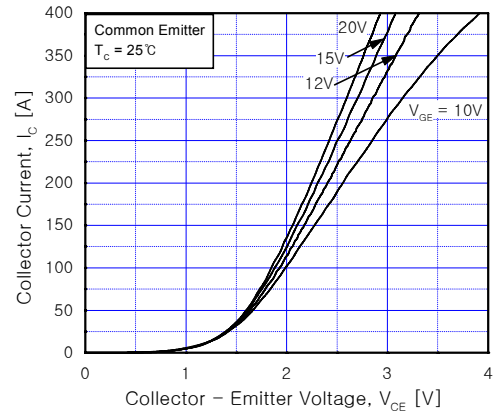


Fig 2. Typical Saturation Voltage Characteristics

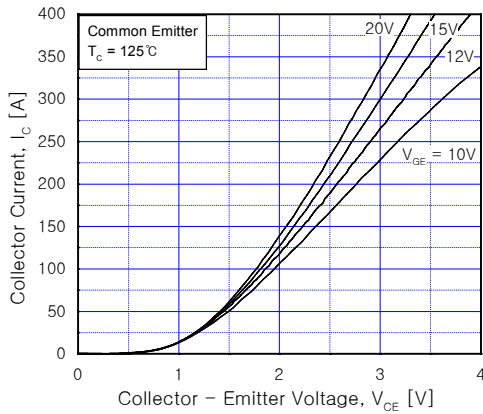


Fig 3. Typical Saturation Voltage Characteristics

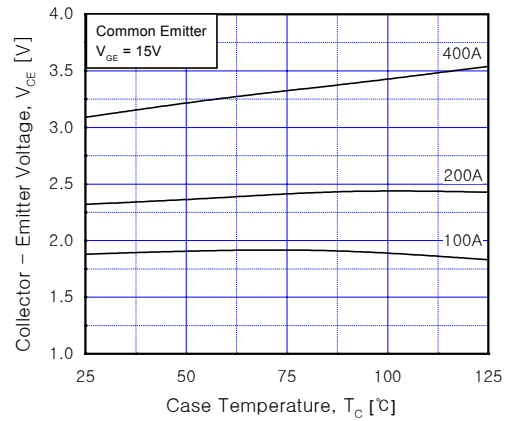


Fig 4. Saturation Voltage vs. Case Temperature at Variant Current Level

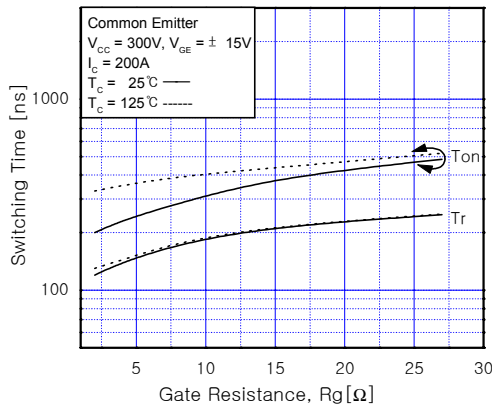


Fig 5. Turn-On Characteristics vs. Gate Resistance

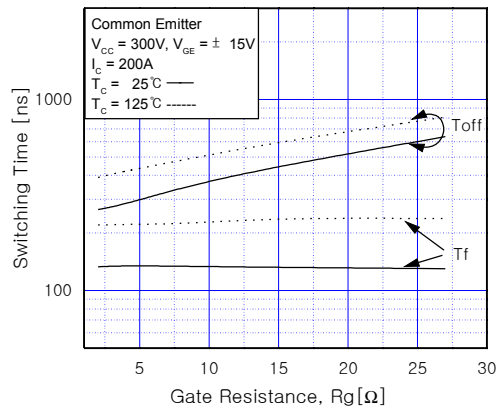


Fig 6. Turn-Off Characteristics vs. Gate Resistance

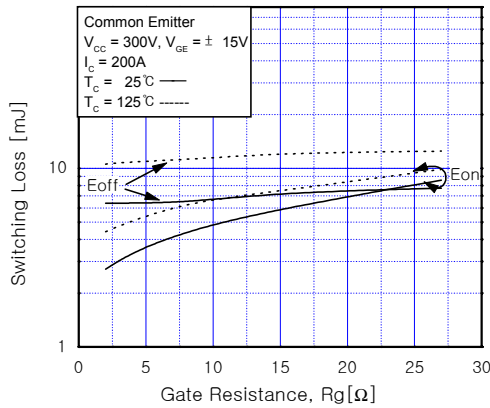


Fig 7. Switching Loss vs. Gate Resistance

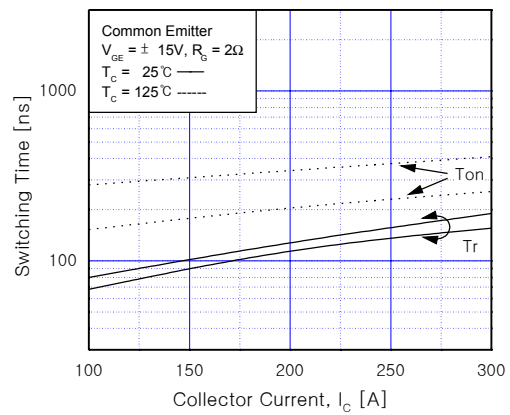


Fig 8. Turn-On Characteristics vs. Collector Current

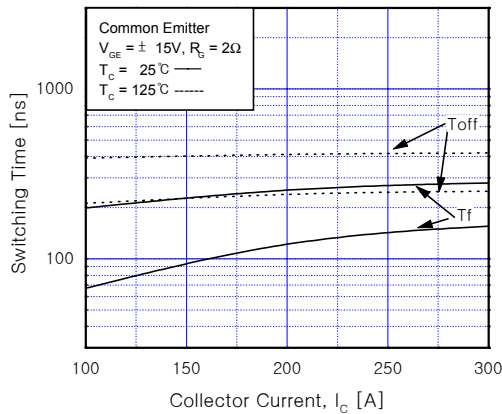


Fig 9. Turn-Off Characteristics vs. Collector Current

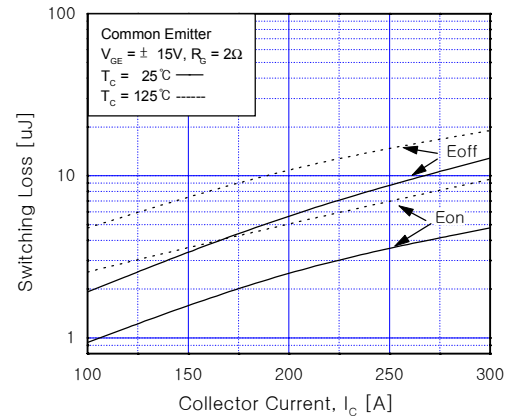


Fig 10. Switching Loss vs. Collector Current

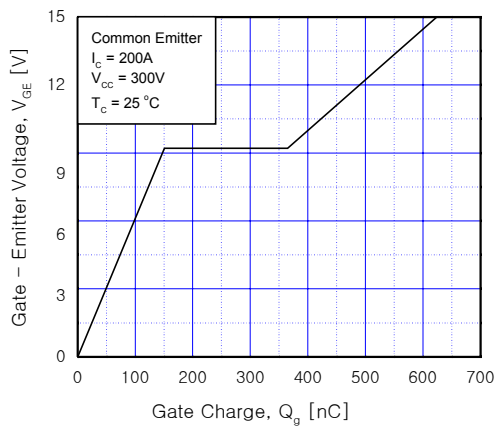


Fig 11. Gate Charge Characteristics

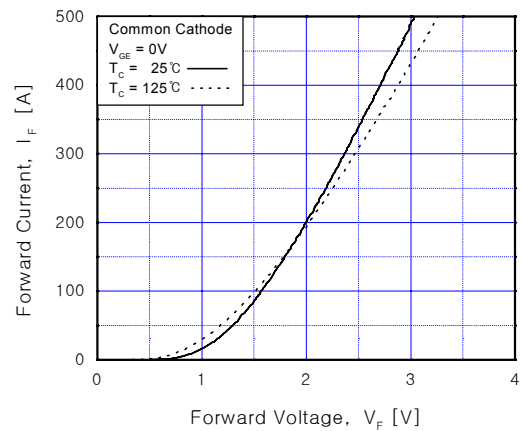


Fig 12. Forward Characteristics(diode)

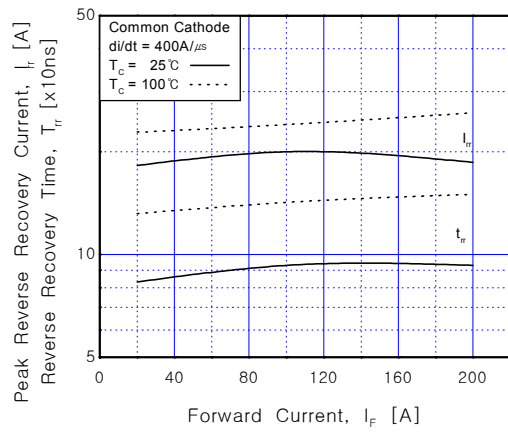
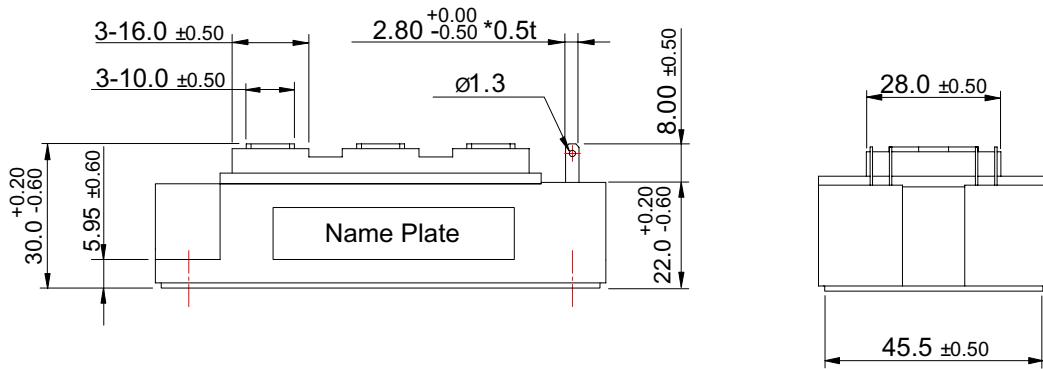
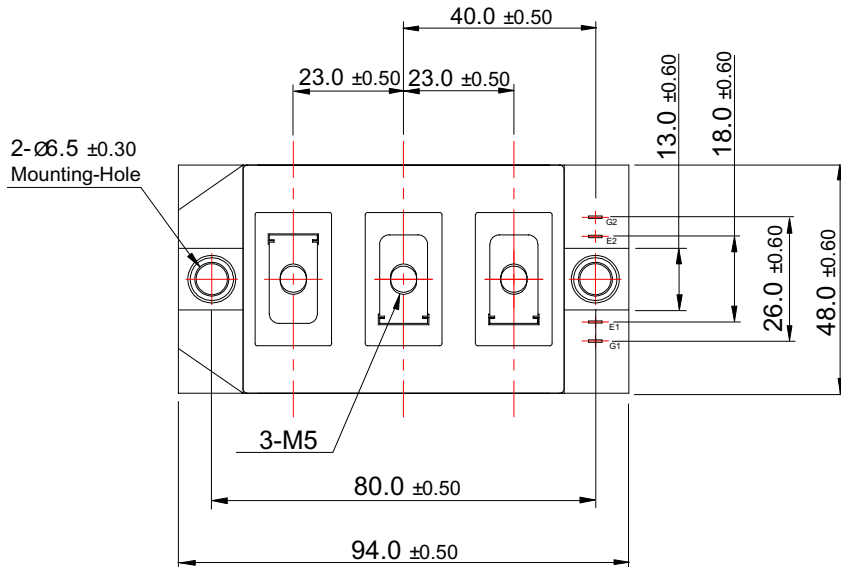


Fig 13. Reverse Recovery Characteristics(diode)

Package Dimension

7PM-HA



Dimensions in Millimeters

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